



**WWW.BRIGHTER.EU
WORKSHOP
CLEO Europe 18th June 2007**

High brightness laser diode sources

**General Introduction
by
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Alcatel-Thales III-V Lab

CHALLENGE:

- Strengthen the position of Europe in High Brightness Laser Diode technology and take a large share of the fast growing € 1 billion market foreseen by the end of the decade.

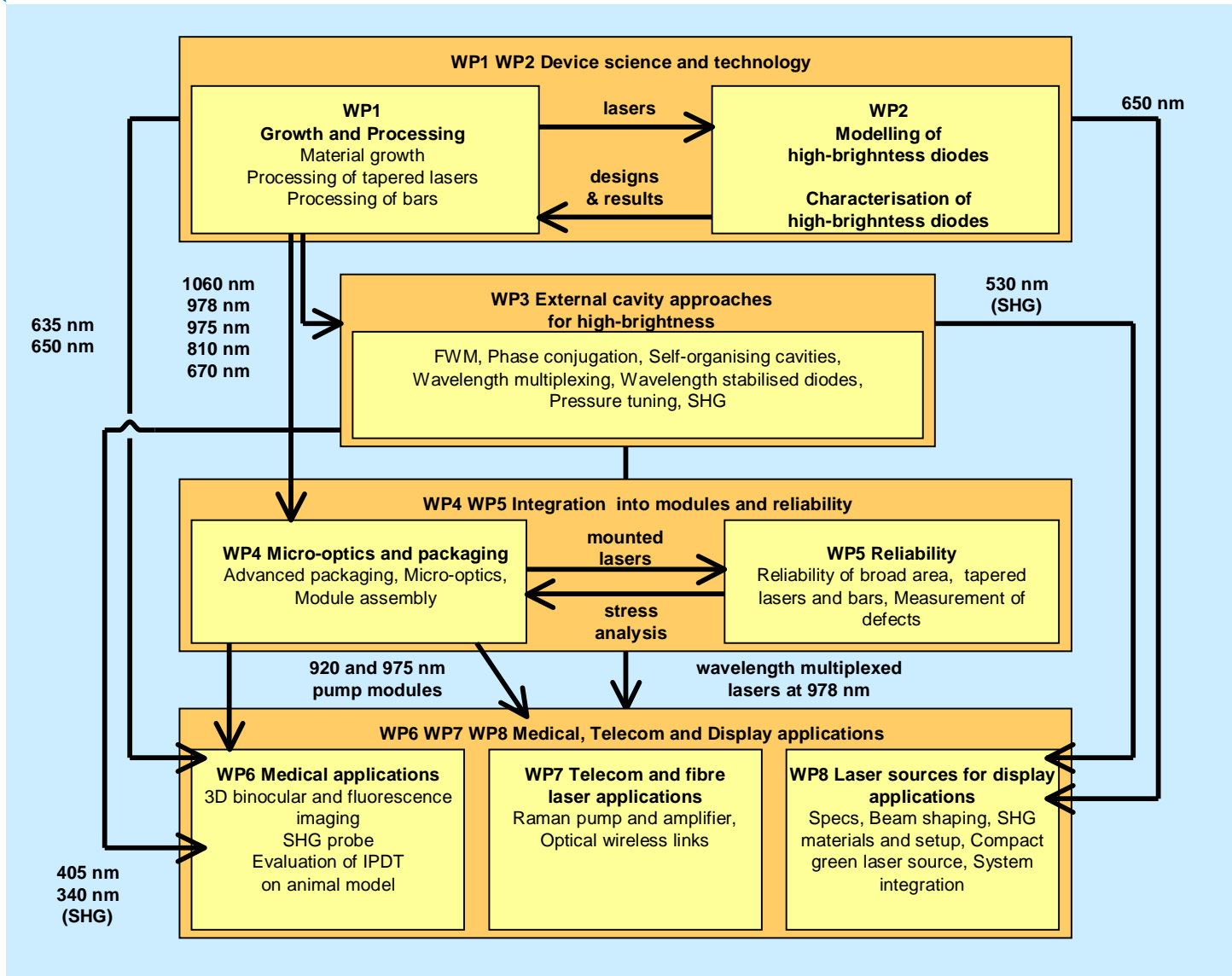
OBJECTIVE:

- Push the limits of current technology (brightness, power and efficiency) - *medium term*
- Develop advanced technologies (high beam coherence, even higher brightness) - *long term*
- Demonstrate applications in the fields of health-care, telecom, display, security and environment.

APPROACH:

- Streamline the technical developments through a coherent exploitation of synergies, leading to pre-industrial demonstrators.
- Accelerate the development and uptake of advanced technologies through partnership between leading Industries, Research Centres and Universities.
- Establish an expert workforce and stimulate new markets by engaging future engineers, industrial players and end-users through training, dissemination and popularisation activities.

WWW.BRIGHTER.EU		
3 years		11 countries involved
8 industrial partners	7 Universities	8 Research centres
24 pre-industrial application demonstrators		



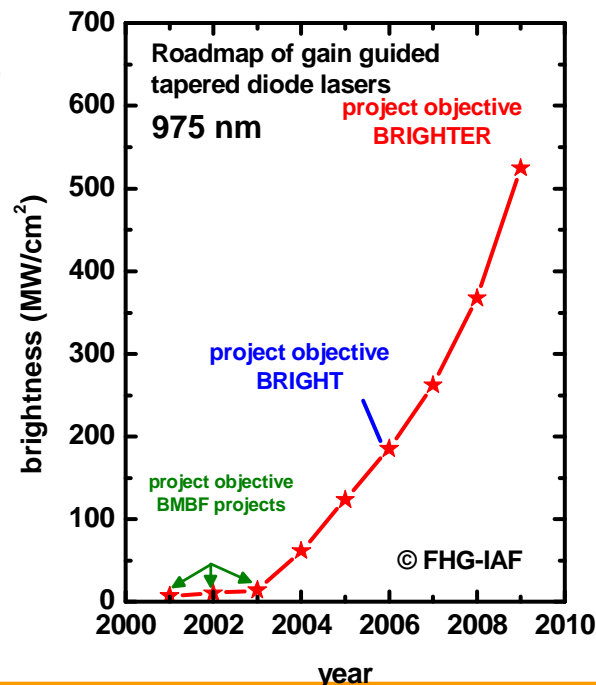


BRIGHTER PARTICIPANTS

No	Country	WWW.BRIGHTER.EU Participant
<u>1</u>	France	Alcatel Thales III-V Lab
<u>2</u>	Germany	Biolitec
<u>3</u>	Sweden	Lund University
<u>4</u>	Greece	Institute of communication and computer Systems
<u>5</u>	Denmark	RISOE National Laboratory
<u>6</u>	Germany	OSRAM Opto Semiconductors
<u>7</u>	United Kingdom	University of Cambridge
8	France	Keopsys
<u>9</u>	France	Alcatel CIT
<u>10</u>	Canada	Institut National d'Optique
<u>11</u>	Germany	University of Würzburg
<u>12</u>	Switzerland	Fisba Optik AG
<u>13</u>	Switzerland	Rainbow Photonics AG
14	France	THALES
<u>15</u>	Spain	Universidad Politecnica de Madrid
<u>16</u>	Germany	Forschungsverbund Berlin e.V. - FBH
<u>17</u>	Germany	Fraunhofer-Gesellschaft
<u>18</u>	Poland	Instytut Wysokich Cisnien PAN (UNIPRESS)
<u>19</u>	Germany	Universität Kassel
<u>20</u>	France	Centre National de la Recherche Scientifique
<u>21</u>	Germany	Forschungsverbund Berlin e.V. - MBI
<u>22</u>	Ireland	Tyndall National Institute
<u>23</u>	United Kingdom	University of Nottingham

► Progress beyond BRIGHT.EU

- QD laser material for 920 nm uncooled pump modules ($d\lambda/dT < 0.1$ nm/K, P: 2 W \rightarrow 4 W, η_p : 50% \rightarrow 60%)
- 635 nm red laser (P: 3 W \rightarrow 5 W, reliability: 1000 h \rightarrow 2000 h)
- 650 nm red laser (P: 4 W \rightarrow 7 W, reliability: 1000 h \rightarrow 2000 h, VFF: 40° \rightarrow 32°)
- Al-free 975 nm Esaki-junction laser (P: 20 W \rightarrow 80 W)
- gain-guided tapered lasers ($M^2 < 2$, P: 5 W \rightarrow 10 W, VFF: 70° \rightarrow 40°)

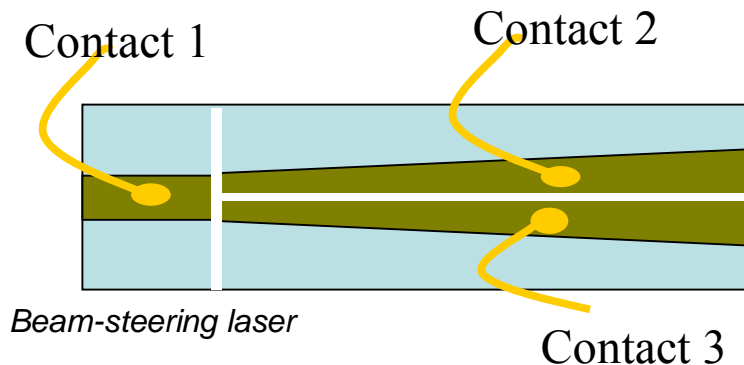


► New BRIGHTER activities

- Zero- α QD laser material with tunnel injection design (920/1060 nm) for reduced filamentation (P > 4 W, $T_0 > 300$ K)
- 1060 nm MOPA laser with integrated overgrown DFB/DBR grating (P > 5 W (single chip), VFF < 22°, $\Delta\lambda < 0.1$ nm)
- High wall-plug efficiency laser structures ($\eta_p = 70\%$)
- 670 nm tapered laser (P > 1 W, $M^2 < 2$)
- Large spot size QD/QW SCOWL (1060 nm, P > 3 W (single chip))
- 975/1060 nm beam steering lasers
- Phase coupled tapered laser mini-arrays
- Injection modulated (> 100 MHz) multi-section lasers (650 nm, 1060 nm)
- Simulation and design of QD lasers
- Simulation/design of external cavity lasers (FWM, self-organizing, Talbot effect cavities)
- Simulation of modulation behavior and modal discrimination in astable cavity lasers

► Progress beyond BRIGHT.EU

- 975 nm pump sources for EDFA:
Increase of power from 5 W →
12 W (50 μ m fibre)
- EDFA for WDM and CATV:
Increase of P_{sat} from +27 dBm →
+33 dBm
- 915 nm pump source for Yb-Laser:
Pump power increased from 10 W
→ **30 W** (200 μ m fibre)
- From laboratory breadboards in
BRIGHT.EU → **modules** in
BRIGHTER



► New BRIGHTER activities

- Raman laser, output power >3 W
(using Yb source)
- Raman amplifier, 18 dB gain,
 $P_{\text{sat}} > 1$ W
- System validation of EDFA and Raman
amplifiers
- Diffuse source optical wireless: High-
speed modulation (max. 1 Gbit/s) of
high-brightness laser at 1060 nm
- Directed line of sight optical wireless:
Beam steerable, high-speed laser at
5 W, $M^2 < 2$, 1060 nm
- Pollutant detection: pulsed Yb fibre
laser at 1070 nm, ns-pulses at 100 kHz
- Laser illuminator for security imaging,
based on Esaki junction lasers, 80 W
peak power from single emitter

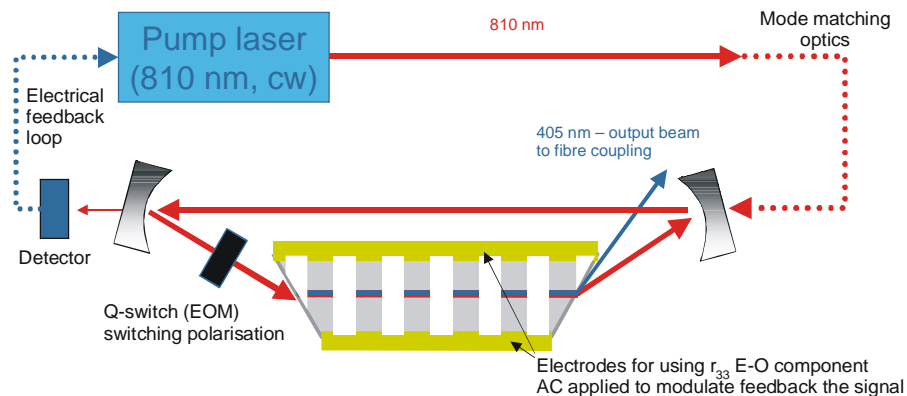
► Progress beyond BRIGHT.EU

- fluorescence diagnostics imaging for use with photosensitisers
 - increased SNR, resolution, and image size
 - SHG into 405 nm from **pulsed**, tapered 810 nm diodes ($M^2 < 1.2$, 5 kHz, **$P > 1W$**)
- double brightness of multi-port, red lasers for I-PDT
 - thinner fibres (200-300 microns), higher power **$P > 7 W$**

► New BRIGHTER activities

- **auto**fluorescence diagnostics imaging of endogenous chromophores, e.g. cancerous lesions
 - SHG into 340 nm ($M^2 < 1.2$, pulsed - 5 kHz, **$P > 0.2W$**)
- extend red PDT laser systems with detection units measuring back-scattered red light during treatment
 - implementation of on-line monitoring of parameters relevant for therapy progress
- application of multi-variate image analysis methods on multi-spectral fluorescence images
 - enables/improves diagnostics

External cavity for SHG



External cavities & Laser displays

EXTERNAL CAVITIES

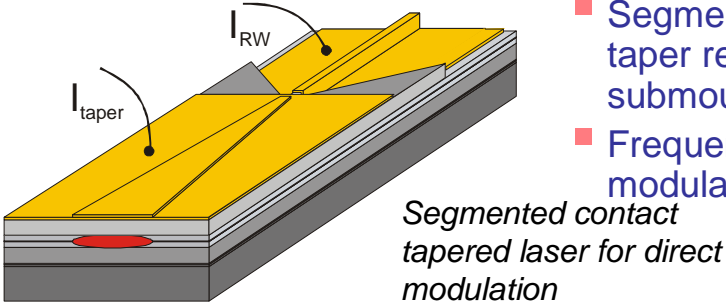
- ▶ **Progress beyond BRIGHT.EU**
 - wavelength multiplexing of stacks of tapered mini-bars
 - >30W in 50 micron fibre

- ▶ **New BRIGHTER activities**
 - external diode setup for investigating FWM-induced carrier density gratings with electroluminescence microscopy
 - essential for modelling and fabrication
 - improved brightness of bars by coherent combining of beams in external Talbot cavities

LASER DISPLAYS

- ▶ **NEW ACTIVITY**
- ▶ **Know-How from BRIGHT.EU**
 - IR and red tapered laser (WP 1)
 - Frequency doubling (WP 3)
 - Optical beam shaping and low-stress mounting (WP 4)
 - Reliability (WP 5)

- ▶ **BRIGHTER activities**
 - Direct MHz modulation of IR and red tapered lasers
 - Integrated wavelength stabilization of tapered lasers
 - Segmented contacts for injection and taper regions and structured submounts
 - Frequency doubling with MHz modulation



Workshop purposes

- **Publicise the activities, technologies, expertise and capacity of both the project and the individual partners.**
- **Learn about the laser needs of different external application fields and organisations active in them.**
- **Establish links and interaction with these fields and external players.**

Workshop at the World of Photonics Congress and Laser2007 fair 18th June 2007 - Munich Program

High Brightness Diode Laser Sources

Workshop Introduction and Welcome (10:30 - 10:35)

10:30 Introduction to WWW.BRIGHTER.EU
Michel Krakowski - Alcatel-Thales III-V Lab

High-Brightness Laser Technology (10:35 - 11:45)

10:35 External cavities for controlling spatial & spectral properties of SC lasers
Jean-Pierre Huignard - Thales Research and Technology

10:45 Reliable high-power red-emitting laser diodes
Bernd Sumpf - Ferdinand Braun Institute

10:55 Wavelength stabilised high-power quantum dot lasers
Hans Peter Reithmaier - University of Kassel

11:05 Quantum dot lasers & new device concepts for high-brightness applications
Dieter Bimberg / Nikolai Ledentsov - Technical University of Berlin

11:25 High-power laser for surgical applications (cutting and ablation)
Ronald Sroka - LFL Munich

Break

Packaging, Micro-Optics and Reliability (12:05 - 12:45)

12:05 Micro-optics and fibre coupling of high-brightness laser bars
Martin Forrer - FISBA Optik

12:15 How to measure packaging-induced strain in high-brightness diode lasers?
Jens Tömm - Max Born Institute

12:25 High-power laser modules and their applications
Jörg Neukum - DILAS

Break

Frequency-Doubled Lasers (14:00 - 14:50)

14:00 Second harmonic generation of external cavity tapered diode lasers
Ole Bjarlin Jensen - Risø National Laboratory

14:10 High-power Semiconductor VECSELS
Anne Tropper - University of Southampton

14:30 ps applications of diode lasers
Ranier Erdmann - Picoquant

Break

Medical, Telecom and Display Applications (15:10 - 17:00)

15:10 Fluorescence diagnostics in medicine - there is a need for improved light sources
Stefan Andersson-Engels - Lund University

15:20 Diode lasers for photodynamic therapy
Tilmann Trebst - Biolitec

15:30 Laser-induced fluorescence spectroscopy and molecular imaging as tools for tumour detection in vivo
Bernd Ebert - Physikalisch-Technische Bundesanstalt

15:50 Shrinking optically-pumped frequency-doubled green semiconductor lasers to fit into tiny laser projectors
Michael Kühnelt - OSRAM Opto Semiconductors

16:10 Laser display markets, technologies and requirements
Holger Mönch - Philips Research Laboratories

16:30 Fibre amplifiers and pumping technologies
Mark Le Flohic - Keopsys

16:40 Making use of brighter lasers - Optical amplifiers in current and future WDM systems
Jörg Peter Ebers - Ericsson

Note: The above program is subject to change at the discretion of the workshop organisers.

